

This listing of the claims will replace all prior versions and listings of the claims in the application.

Listing of the Claims:

1. (Previously Presented) An object detection system comprising
a retroreflector; and
a emitter-detector assembly having a light emission area from which a light beam is emitted toward the retroreflector and having a light detection area in which light impinging thereon from the retroreflector produces an electrical signal, wherein the light emission area and the light detection area are concentric with one extending around the other;
wherein the object detection system has a quality factor Q that is greater than 0.25,
where the quality factor is given by the expression:

$$Q = (R_s S_{rf}) / (R_d S_{rr} G_{max})$$

in which R_s is a signal produced by the emitter-detector assembly in response to returned light from a retroreflector, S_{rf} is the size of the field of view in steradians of the light detection area, and S_{rr} is the size in steradians of the light beam that is subtended by the retroreflector, R_d is the signal produced by the emitter-detector assembly in response to returned light from a 100% uniformly diffuse surface, and G_{max} is a maximum reflectance of the retroreflector compared to light returned from a 100% uniformly diffuse surface.

2. (Original) The object detection system as recited in claim 1 wherein the light emission area extends around the light detection area.

3. (Original) The object detection system as recited in claim 2 wherein the light detection area comprises a photodetector and the light emission area comprises a plurality of light emitters located at different angles axially around the photodetector.

4. (Original) The object detection system as recited in claim 1 wherein the light detection area extends around the light emission area.

5. (Original) The object detection system as recited in claim 4 wherein the light emission area comprises a light emitter, and the light detection area comprises a plurality of photodetectors located at different angles axially around the light emitter.

6. (Previously Presented) An object detection system comprising:

a retroreflector; and

a emitter-detector assembly having a light emission area from which a light beam is emitted toward the retroreflector and having a light detection area in which light impinging thereon from the retroreflector produces an electrical signal, wherein the light emission area and the light detection area are concentric with one extending around the other;

wherein the light detection area is substantially equal in size to the light emission area.

7. (Previously Presented) The object detection system as recited in claim 6 wherein the emitter-detector assembly further comprises a housing having an inner chamber in which one of the light detection area and the light emission area is located, and an annular outer chamber in which the other one of the light detection area and the light emission area is located.

8. (Cancelled)

9. (Previously Presented) The object detection system as recited in claim 6 having a quality factor Q that is greater than 0.25, where the quality factor is given by the expression:

$$Q = \iint [Gr(x) dS dD] / (A_s A_d)$$

where A_s is the size of the light emission area, A_d is the size of the light detection area, dS is an area element of the light emitting aperture, dD is an area element of the photodetector aperture, x is the separation between the source aperture and detector aperture area elements, and $Gr(x)$ is the relative gain of the retroreflector at the displacement x between source and detector area elements compared to the maximum attainable return.

10. (Previously Presented) The object detection system as recited in claim 6 wherein the light emission area comprises at least one light emitter selected from the group consisting of a light emitting diode, a laser, an incandescent bulb, a fluorescent bulb, a phosphorescent emitter, and an electroluminescent emitter.

11. (Previously Presented) The object detection system as recited in claim 6 wherein the light detection area comprises at least one device selected from the group consisting of a photodiode, a phototransistor, a thermopile, a solid state imager, a photomultiplier tube, and a pyroelectric detector.

12. (Currently Amended) An emitter-detector assembly for object detection system having a retroreflector, the emitter-detector assembly comprising:

a light emission section comprising a light emitter assembly from which a light beam emanates in a first path; and

a light detection section comprising a photodetector which produces an electrical signal in response to light impinging thereon from the retroreflector; ~~wherein the light emitter assembly is concentric with the light detection section~~

wherein the light emitter assembly is concentric with the light detection section, and comprises a plurality of light emitters located at different angles axially around the photodetector.

13. (Canceled)

14. (Previously Presented) The emitter-detector assembly as recited in claim 12 wherein the light detection section comprises a photodetector and the light emitter assembly extends around the photodetector.

15. (Original) The emitter-detector assembly as recited in claim 12 wherein the light emission section comprises at least one light emitter selected from the group consisting of a light emitting diode, a laser, an incandescent bulb, a fluorescent bulb, a phosphorescent emitter, and an electroluminescent emitter.

16. (Original) The emitter-detector assembly as recited in claim 12 wherein the light detection section comprises at least one device selected from the group consisting of a photodiode, a phototransistor, a thermopile, a solid state imager, a photomultiplier tube, and a pyroelectric detector.

17. (Original) The emitter-detector assembly as recited in claim 12 wherein the light detection section is substantially equal in cross-sectional area to the light emission section.

18. (Previously Presented) The emitter-detector assembly as recited in claim 12 having a quality factor Q that is greater than 0.25, where the quality factor is given by the expression:

$$Q = \iint [Gr(x) dS dD] / (A_s A_d)$$

where A_s is the size of the light emission section, A_d is the size of the light detection section, dS is an area element of the light emitting aperture, dD is an area element of the photodetector aperture, x is the separation between the source aperture and detector aperture section area elements, and $Gr(x)$ is the relative gain of the retroreflector at the displacement x between source and detector section area elements compared to the maximum attainable return.

19. (Original) The emitter-detector assembly as recited in claim 12 further comprising a housing having an inner chamber in which one of the light detection section and the light emission section is located, and an annular outer chamber extending around the inner chamber and in which the other one of the light detection section and the light emission section is located.